

Abstract Submitted  
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**The measurements of thermopower and thermal conductivity of an  $\text{In}_2\text{O}_3$  nanowire through a general purpose template** MIN-NAN OU, PING-CHUNG LEE, CHENG-LUNG CHEN, Institute of Physics, Academia Sinica, CHIEN-LIN HUNG, LI-JEN CHOU, Materials Science and Engineering, NTHU, YANG-YUAN CHEN, Institute of Physics, Academia Sinica — In order to study the electron-phonon transport properties in a single nanowire for various materials, a platform of Si/Si<sub>3</sub>N<sub>4</sub> for the purpose was designed to perform the measurements of thermal power and thermal conductivity simultaneously. A single  $\text{In}_2\text{O}_3$  nanowire was placed on the platform by manipulation probes and carefully examined. A sagging structure of  $\text{In}_2\text{O}_3$  nanowire was prepared by E-beam lithographic and reactive ion etching techniques. The  $\text{In}_2\text{O}_3$  nanowire with length of 30  $\mu\text{m}$  and diameter of 100 nm was revealed by SEM images, The resistivity measured using four-probe method indicated a semiconducting like behavior in the range temperature from 10 K to 300 K with room-temperature resistivity about 2.17 m $\Omega$ -cm at 300 K. Meanwhile, the thermopower and the thermal conductivity of  $\text{In}_2\text{O}_3$  nanowire measured by steady state and self-heating  $3\omega$  method respectively are also obtained and was discussed in details.

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